

FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

Attorney Docket No.:

MUH-12041

Applic. No.

09/997,983

Applicant

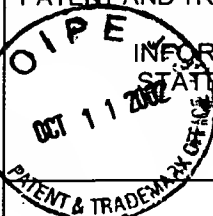
Heinz Hönigschmid

Filing Date

November 29, 2001

Group Art Unit

2818 2185



U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
TP	A	5,940,319	08/17/99	Durlam et al.			
TP	B	6,097,625	08/01/00	Scheuerlein			
	C						
	D						
	E						
	F						
	G						
	H						
	I						

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OCT 15 2002

Technology Center 2100

FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
	J						
	K						
	L						
	M						
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

TP	O	M. Durlam et al.: "Nonvolatile RAM based on Magnetic Tunnel Junction Elements", 2000 IEEE International Solid-State Circuits Conference, Digest of Technical Papers, pp. 130-131
TP	P	S. Tehrani et al.: "Recent Developments in Magnetic Tunnel Junction MRAM", IEEE Transactions on Magnetics, Vol. 36, No. 5, September 2000, pp. 2752-2757

EXAMINER

Trong Phan

DATE CONSIDERED

9/28/03

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.